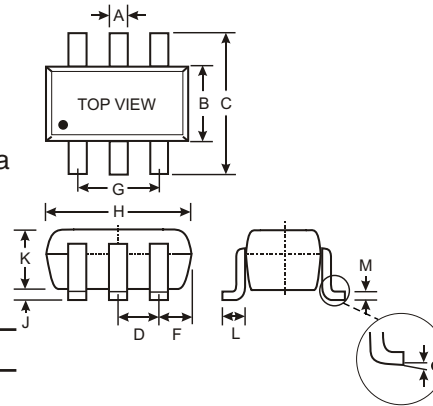


### Features

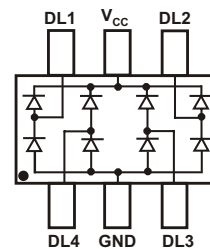
- Low Forward Voltage Drop
- Fast Switching
- Very High Density
- Ultra-Small Surface Mount Package
- PN Junction Guard Ring for Transient and ESD Protection
- Provide transient protection for high-speed data lines in accordance with:  
IEC61000-4-2 (ESD) 15kV (Air), 8kV (Contact)  
IEC61000-4-4 (EFT) 80A (tp = 5/50 ns)  
IEC61000-4-5 (Lightning) Class 3



SOT-363		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
F	0.30	0.40
H	1.80	2.20
J	—	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.25
α	0°	8°
All Dimensions in mm		

### Mechanical Data

- Case: SOT-363, Molded Plastic
- Case material - UL Flammability Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 0.006 grams (approx.)
- Marking Code: KST (See Page 2)



### Maximum Ratings @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	30	V
Working Peak Reverse Voltage	V <sub>RWM</sub>		
DC Blocking Voltage	V <sub>R</sub>		
Forward Continuous Current (Note 1)	I <sub>FM</sub>	200	mA
Non-Repetitive Peak Forward Surge Current @ t < 1.0s	I <sub>FSM</sub>	600	mA
Power Dissipation (Note 1)	P <sub>d</sub>	200	mW
Thermal Resistance Junction to Ambient Air (Note 1)	R <sub>θJA</sub>	625	°C/W
Operating Temperature Range	T <sub>j</sub>	-55 to +125	°C
Storage Temperature Range	T <sub>STG</sub>	-65 to +125	°C

### Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 2)	V <sub>(BR)R</sub>	30	—	—	V	I <sub>R</sub> = 100μA
Forward Voltage (Note 2)	V <sub>F</sub>	—	—	280 350 450 550 1000	mV	I <sub>F</sub> = 0.1mA, tp < 300μS I <sub>F</sub> = 1.0mA, tp < 300μS I <sub>F</sub> = 10mA, tp < 300μS I <sub>F</sub> = 30mA, tp < 300μS I <sub>F</sub> = 100mA, tp < 300μS
Reverse Current (Note 2)	I <sub>R</sub>	—	—	2	μA	V <sub>R</sub> = 25V
Total Capacitance (Note 3)	C <sub>T</sub>	—	10.0	—	pF	V <sub>R</sub> = 0, f = 1.0MHz
Reverse Recovery Time	t <sub>rr</sub>	—	—	5.0	ns	I <sub>F</sub> = I <sub>R</sub> = 10mA, I <sub>rr</sub> = 0.1 x I <sub>R</sub> , R <sub>L</sub> = 100Ω

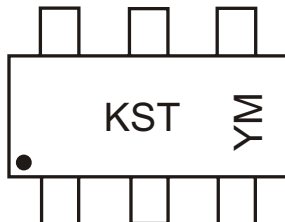
- Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.  
2. Short duration test pulse used to minimize self-heating effect.  
3. At V<sub>R</sub> = 0V, DL(X) to V<sub>CC</sub> or GND.

**Ordering Information** (Note 4)

Device	Packaging	Shipping
QSBT40-7	SOT-363	3000/Tape & Reel

Notes: 4. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

**Marking Information**



KST = Product Type Marking Code  
 YM = Date Code Marking  
 Y = Year ex: N = 2002  
 M = Month ex: 9 = September

Date Code Key

Year	2001	2002	2003	2004	2005	2006	2007	2008	2009
Code	M	N	P	R	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D